

All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

_,	Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
	I _{CES}	Zero Gate Voltage Collector Current	age Collector Current $V_{GE} = 0V, V_{CE} = 1200V$				250	μΑ
,	V _{CE(sat)}	Collector Emitter saturation Voltage	, GE 10 ,	$T_j = 25^{\circ}C$	1.4	1.7	2.1	V
	V CE(sat)			$T_j = 125$ °C		2.0		v
	$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 3 \text{ mA}$		5.0		6.5	V
	I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V$, $V_{CE} = 0V$				400	nA

Dynamic Characteristics

·	Characteristic	Test Conditions		Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			5340		
C_{oes}	Output Capacitance	$V_{CE} = 25V$			280		pF
C_{res}	Reverse Transfer Capacitance	f = 1MHz			240		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)			260		ns
T_{r}	Rise Time		$V_{GE} = \pm 15V$		30		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 75A$			420		
T_{f}	Fall Time	$R_G = 4.7\Omega$		70			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ing (125°C)		285		
T_{r}	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 75A$			50		ns
$T_{d(off)}$	Turn-off Delay Time				520		
$T_{\rm f}$	Fall Time	$R_G = 4.7\Omega$			90		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		7		m I
E_{off}	Turn-off Switching Energy	$I_{C} = 75A$ $R_{G} = 4.7\Omega$	$T_j = 125$ °C		8.1		mJ

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V	
I_{RM}	Maximum Reverse Leakage Current	V _R =1200V	$T_j = 25^{\circ}C$			250	μA	
1RM	Waximum Reverse Leakage Current		$T_{j} = 125^{\circ}C$			500	μΛ	
I_F	DC Forward Current	$I_F = 75A$	$Tc = 80^{\circ}C$		75		A	
V_{F}	Diode Forward Voltage		$T_i = 25^{\circ}C$		1.5	2.0	V	
V F	Diode Forward Voltage	IF /JA	$T_{i} = 125^{\circ}C$		1.4			
t _{rr}	Reverse Recovery Time	$I_F = 75 A$ $V_R = 600 V$ $di/dt = 2000 A/\mu s$	$T_j = 25^{\circ}C$		150		ns	
·IT	reverse recovery Time			$T_j = 125$ °C		250		115
Q_{rr}	Reverse Recovery Charge		$T_j = 25^{\circ}C$		7		μС	
Qrr					$T_j = 125$ °C		13.5	
$E_{\rm r}$	Reverse Recovery Energy		$T_j = 25^{\circ}C$		3.7		mJ	
$\mathbf{E}_{\mathbf{r}}$	Reverse Recovery Ellergy		$T_{j} = 125^{\circ}C$		7.2		1117	



Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

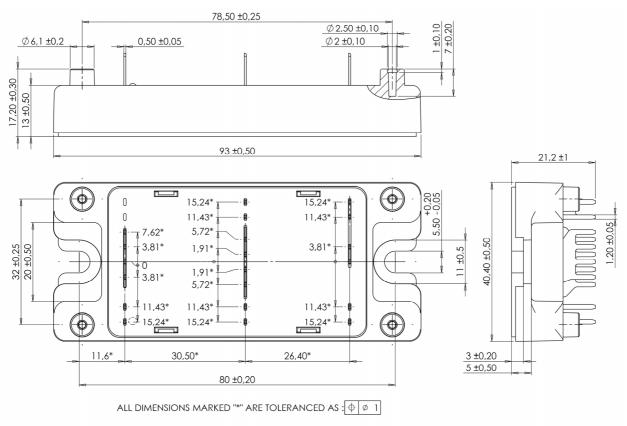
Symbol	Characteristic	Min	Тур	Max	Unit	
R ₂₅	Resistance @ 25°C		50		kΩ	
${ m B}_{25/85}$	$T_{25} = 298.15 \text{ K}$		3952		K	

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.35	°C/W
TthJC			Diode			0.48	C/ 11
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz		4000			V	
T_{J}	Operating junction temperature range		-40		150		
T_{STG}	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature		-40		125		
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight				160	g	

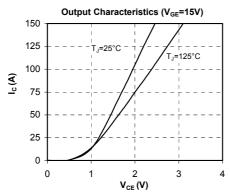
SP4 Package outline (dimensions in mm)

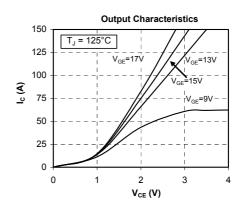


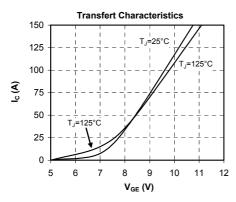
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

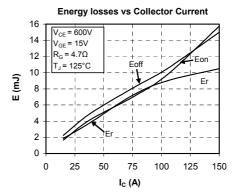


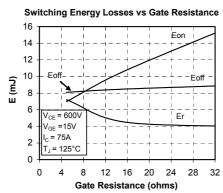
Typical Performance Curve

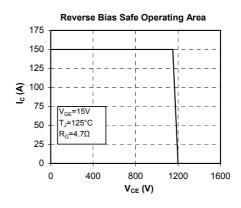


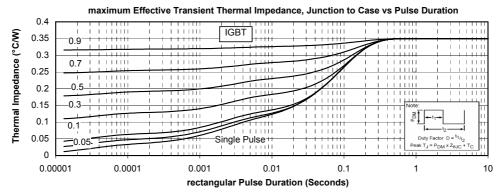




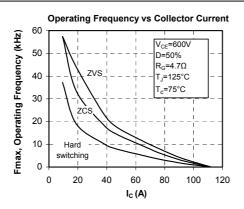


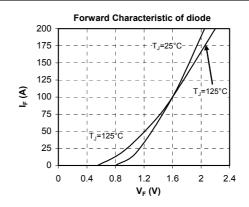


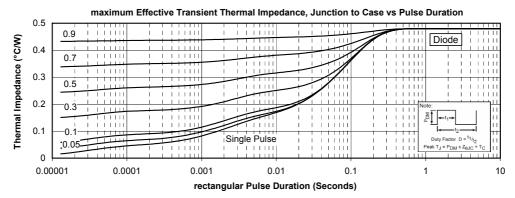














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